

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	7474	((438/30) or (438/128) or (438/149) or (438/150) or (438/151) or (438/166) or (438/308) or (438/488) or (438/489) or (438/491) or (438/795) or (438/799)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/29 21:12
L2	10	1 and ((laser or (laser near2 beam)) same reciprocal\$2)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/29 21:12
L3	6	2 and (active near2 matrix)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/29 21:13
S1	4841	((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/29 17:42
S2	0	quasi near2 strip near2 like near2 crystal	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:35
S3	2	quasi near2 strip near2 like	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 21:24
S4	1188	polycrystalline same recrystallization	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 21:25
S5	0	((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.) and (quasi near2 strip near2 like)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 21:25
S6	7080	reformation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 21:25

S7	83908	polycrystalline	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:21
S8	6	reformation same polycrystalline	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 21:27
S9	84120	polycrystalline or (p adj si adj (layer or film))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:30
S10	156387	anneal or annealing	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 21:29
S11	5374	(polycrystalline or (p adj si adj (layer or film))) same (anneal or annealing)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 21:29
S12	681508	laser	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:37
S13	1662	laser same ((polycrystalline or (p adj si adj (layer or film))) same (anneal or annealing))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 21:30
S14	2666	lateral near2 growth	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 21:30
S15	23	(laser same ((polycrystalline or (p adj si adj (layer or film))) same (anneal or annealing))) same (lateral near2 growth)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 21:30
S16	5	((("200243222") or ("2002100637"))).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/01/11 21:39

S17	202391	irradiate or irradiating	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:34
S18	89	((irradiate or irradiating) near (polycrystalline or (p adj si adj (layer or film))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:21
S19	5342	((438/30) or (438/128) or (438/149) or (438/166) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/01/11 22:17
S20	26893	reform or reformation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:19
S21	0	((irradiate or irradiating) near (polycrystalline or (p adj si adj (layer or film)))) same (reform or reformation)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:19
S22	0	((irradiate or irradiating) near (polycrystalline or (p adj si adj (layer or film)))) and (reform or reformation)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:19
S23	25571	pulse near laser	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:21
S24	369	(pulse near laser) same (polycrystalline or (p adj si adj (layer or film))))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:22
S25	177	((pulse near laser) same (polycrystalline or (p adj si adj (layer or film)))) and (irradiate or irradiating)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:22
S26	41017	(polycrystalline or (p adj si)) near2 (layer or film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:33

S27	41	selective near irradiating	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:34
S28	1	((polycrystalline or (p adj si)) near2 (layer or film)) and (selective near Irradiating)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:32
S29	17	(irradiate or irradiating) near (selective near irradiating)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:35
S30	0	((irradiate or irradiating) near ((polycrystalline or (p adj si)) near2 (layer or film))) and (quasi near like)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:35
S31	104	(irradiate or irradiating) near ((polycrystalline or (p adj si)) near2 (layer or film))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:40
S32	101	sequential near lateral near solidification	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:41
S33	55	(sequential near lateral near solidification) and ((polycrystalline or (p adj si)) near2 (layer or film))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/11 22:42
S34	103	quasi near like	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/01/12 10:20
S35	2	(("20010026835") or ("20020031876")).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2004/05/14 16:03
S36	5077	((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/05/14 19:32

S37	42208	(polycrystalline or (p adj si)) near2 (layer or film)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:33
S38	354399	irradiate or irradiating or irradiation	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:34
S39	255093	crystallize or crystallizing or crystallization or recrystallize or recrystallizing or recrystallization	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:35
S40	23926	((a adj si) or (amorphous near2 silicon)) near (film or layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:36
S41	711816	laser	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:37
S42	163809	anneal or annealing	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:37
S43	4110	((polycrystalline or (p adj si)) near2 (layer or film)) and (irradiate or irradiating or irradiation)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:37
S44	1995	((((polycrystalline or (p adj si)) near2 (layer or film)) and (irradiate or irradiating or irradiation)) and (crystallize or crystallizing or crystallization or recrystallize or recrystallizing or recrystallization))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:37
S45	1384	(((((polycrystalline or (p adj si)) near2 (layer or film)) and (irradiate or irradiating or irradiation)) and (crystallize or crystallizing or crystallization or recrystallize or recrystallizing or recrystallization)) and (((a adj si) or (amorphous near2 silicon)) near (film or layer)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:37

S46	1311	((((polycrystalline or (p adj si)) near2 (layer or film)) and (irradiate or irradiating or irradiation)) and (crystallize or crystallizing or crystallization or recrystallize or recrystallizing or recrystallization)) and (((a adj si) or (amorphous near2 silicon)) near (film or layer))) and laser	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:37
S47	1154	((((polycrystalline or (p adj si)) near2 (layer or film)) and (irradiate or irradiating or irradiation)) and (crystallize or crystallizing or crystallization or recrystallize or recrystallizing or recrystallization)) and (((a adj si) or (amorphous near2 silicon)) near (film or layer))) and laser) and (anneal or annealing)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:38
S48	208	((((polycrystalline or (p adj si)) near2 (layer or film)) and (irradiate or irradiating or irradiation)) and (crystallize or crystallizing or crystallization or recrystallize or recrystallizing or recrystallization)) and (((a adj si) or (amorphous near2 silicon)) near (film or layer))) and laser) and (anneal or annealing)) and (((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:40
S49	37776	active near2 matrix	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:40
S50	162	((((polycrystalline or (p adj si)) near2 (layer or film)) and (irradiate or irradiating or irradiation)) and (crystallize or crystallizing or crystallization or recrystallize or recrystallizing or recrystallization)) and (((a adj si) or (amorphous near2 silicon)) near (film or layer))) and laser) and (anneal or annealing)) and (((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.) and (active near2 matrix)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:40

S51	59309	channel near2 region	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:41
S52	133	(((((((((polycrystalline or (p adj si)) near2 (layer or film)) and (irradiate or irradiating or irradiation)) and (crystallize or crystallizing or crystallization or recrystallize or recrystallizing or recrystallization)) and (((a adj si) or (amorphous near2 silicon)) near (film or layer))) and laser) and (anneal or annealing)) and (((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.)) and (active near2 matrix)) and (channel near2 region)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:41
S53	17872	pixel near2 region	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:41
S54	71	(((((((((polycrystalline or (p adj si)) near2 (layer or film)) and (irradiate or irradiating or irradiation)) and (crystallize or crystallizing or crystallization or recrystallize or recrystallizing or recrystallization)) and (((a adj si) or (amorphous near2 silicon)) near (film or layer))) and laser) and (anneal or annealing)) and (((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.)) and (active near2 matrix)) and (channel near2 region)) and (pixel near2 region)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/05/14 19:41
S55	5362	((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 21:40
S56	28	((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.) and (intermittent\$3 same irradiat\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 21:46

S57	1	((((438/30) or (438/128) or (438/149) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.) and ((intermittent\$3 same irradiat\$4) same peripheral near2 side\$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 21:46
S58	6070	((438/30) or (438/128) or (438/149) or (438/166) or (438/488) or (438/489) or (438/491) or (438/795) or (438/799)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/09/30 21:46
S59	47	((((438/30) or (438/128) or (438/149) or (438/166) or (438/488) or (438/489) or (438/491) or (438/795) or (438/799)).CCLS.) and (intermittent\$3 same irradiat\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 21:46
S60	1	(((((438/30) or (438/128) or (438/149) or (438/166) or (438/488) or (438/489) or (438/491) or (438/795) or (438/799)).CCLS.) and (intermittent\$3 same irradiat\$4)) and ((intermittent\$3 same irradiat\$4) same peripheral near2 side\$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 21:47
S61	1	((((438/30) or (438/128) or (438/149) or (438/166) or (438/488) or (438/489) or (438/491) or (438/795) or (438/799)).CCLS.) and ((intermittent\$3 same irradiat\$4) same peripheral near2 side\$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/09/30 21:47
S62	7	((("20030181043") or ("6713324") or ("20010026835") or ("20030068836") or ("6797550") or ("20030166315") or ("20030227038")).PN.	US-PGPUB; USPAT	OR	OFF	2005/03/29 14:54
S63	1	("20040082090").PN.	US-PGPUB	OR	OFF	2005/03/29 14:54
S64	6877	((438/30) or (438/128) or (438/149) or (438/150) or (438/151) or (438/308) or (438/488) or (438/489) or (438/491) or (438/795)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/29 21:11
S65	8	S64 and ((laser or (laser near2 beam)) same reciprocal\$2)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/29 21:12

S66	5	S65 and (active near2 matrix)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/29 21:12
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